NSN 5961-00-152-4591

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-152-4591 **Inclosure Material:** Metal **Overall Length:** Between 0.300 inches and 0.405 inches **Mounting Facility Quantity: Electrode Internally-electrically Connected To Case:** Anode **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 0.423 inches and 0.438 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 120.0 regulator voltage **Current Rating Per Characteristic:** 380.00 milliamperes peak reverse surge current **Power Rating Per Characteristic:** 10.0 watts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius case **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 1 tab, solder lug Shelf Life: N/a **Unit Of Measure:**

Demilitarization: No

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